

PSMN1R0-80CSE

N-channel, 80 V, 0.95 mOhm, MOSFET with enhanced SOA in CCPAK1212i package

6 December 2024

Product data sheet

1. General description

N-channel enhancement mode MOSFET in a CCPAK1212i package qualified to 175 °C. Part of Nexperia's Application Specific MOSFETs (ASFETs) for Hotswap and Soft Start. The PSMN1R0-80CSE delivers very low R_{DSon} and enhanced safe operating area performance in a high-reliability copper-clip package (CCPAK1212i).

PSMN1R0-80CSE complements the latest "hot-swap" controllers - robust enough to withstand substantial inrush currents during turn-on, low R_{DSon} to minimize I^2R losses and deliver optimum efficiency when turned fully ON.

2. Features and benefits

- · Fully optimized Safe Opertating Area (SOA) for superior linear mode operation
- Low R_{DSon} for low I²R conduction losses
- CCPAK1212i package for applications that demand the highest performance and reliability
- Inverted package, suitable for top-side cooling

3. Applications

- Hot swap
- · Load switch
- Soft start
- E-fuse
- · Telecommunication systems based on a 48 V backplane/supply rail

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C	-	-	80	V
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	-	-	495	Α
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>	-	-	1.55	kW
Static charact	eristics					
R _{DSon}	drain-source on-state resistance	$V_{GS} = 10 \text{ V}; I_D = 25 \text{ A}; T_j = 25 ^{\circ}\text{C};$ Fig. 11	-	0.76	0.95	mΩ
Dynamic char	acteristics				'	
Q_{GD}	gate-drain charge	I _D = 25 A; V _{DS} = 40 V; V _{GS} = 10 V; T _j = 25 °C; <u>Fig. 13</u> ; <u>Fig. 14</u>	13	42.5	98	nC
Source-drain	diode				'	
Q _r	recovered charge	I_S = 25 A; dI_S/dt = -100 A/µs; V_{GS} = 0 V; V_{DS} = 40 V; T_j = 25 °C; Fig. 17	-	101	-	nC



5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source		
2	S	source		
3	S	source	12 11 10 9 8 7	
4	S	source		
5	S	source		
6	G	gate		D
7	D	drain		
8	D	drain		G T T
9	D	drain		mbb076 S
10	D	drain	1 2 3 4 5 6	
11	D	drain	sot8005a_sv	
12	D	drain	CCPAK1212i (SOT8005A)	
mb	D	mounting base; connected to drain		

6. Ordering information

Table 3. Ordering information

Type number	Package	ckage				
	Name	Description	Version			
PSMN1R0-80CSE		Plastic, surface mounted copper clip package (CCPAK1212i); 12 terminals; 2.0 mm pitch, 12 mm × 12 mm × 2.5 mm body	SOT8005A			

7. Marking

Table 4. Marking codes

Type number	Marking code
PSMN1R0-80CSE	XP1E0S80C

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). T_i = 25 °C unless otherwise stated.

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	80	V
V_{DGR}	drain-gate voltage	25 °C ≤ T_j ≤ 175 °C; R_{GS} = 20 kΩ		-	80	V
V _{GS}	gate-source voltage			-20	20	V
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	1.55	kW
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>		-	495	Α
		V _{GS} = 10 V; T _{mb} = 100 °C; <u>Fig. 2</u>		-	495	А
I _{DM}	peak drain current	pulsed; $t_p \le 10 \mu s$; $T_{mb} = 25 °C$; Fig. 3		-	3365	А
T _{stg}	storage temperature			-55	175	°C
Tj	junction temperature			-55	175	°C
T _{sld(M)}	peak soldering temperature			-	260	°C
Source-drain	diode			-	'	
Is	source current	T _{mb} = 25 °C		-	420	Α
I _{SM}	peak source current	pulsed; t _p ≤ 10 μs; T _{mb} = 25 °C		-	3365	Α
Avalanche ru	ggedness					
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	I_D = 129 A; $V_{sup} \le 80$ V; R_{GS} = 50 Ω; V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; unclamped; t_p = 282 μs; Fig. 4	[1]	-	1890	mJ
I _{AS}	non-repetitive avalanche current	$V_{sup} \le 80 \text{ V}; V_{GS} = 10 \text{ V}; T_{j(init)} = 25 \text{ °C}; R_{GS} = 50 \Omega; Fig. 4$	[1]	-	129	А

^[1] Protected by 100% test

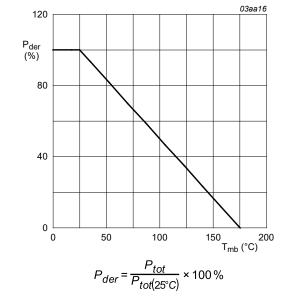
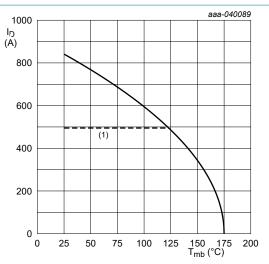


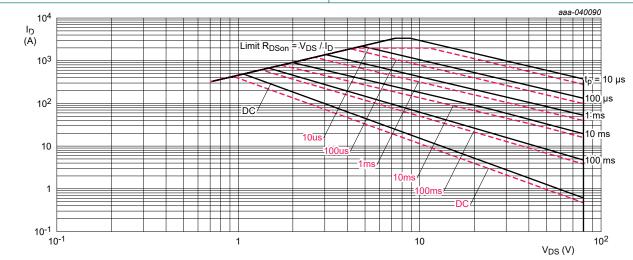
Fig. 1. Normalized total power dissipation as a function of mounting base temperature



V_{GS} ≥ 10 V

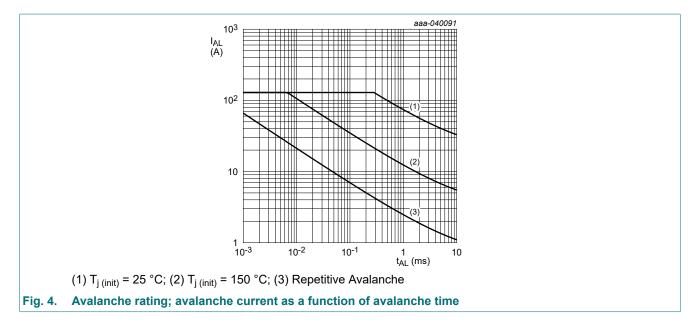
(1) 495 A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

Fig. 2. Continuous drain current as a function of mounting base temperature



 T_{mb} = 25 °C (solid black line); T_{mb} = 125 °C (red dashed line); I_{DM} is a single pulse

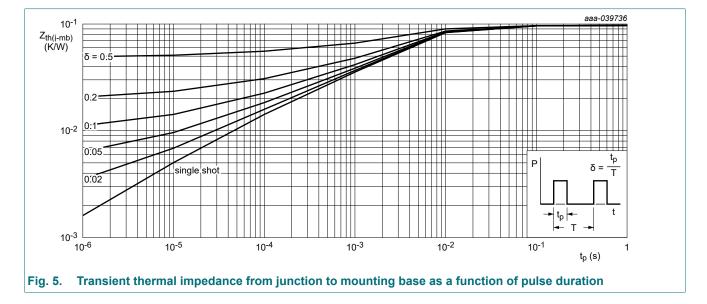
Fig. 3. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

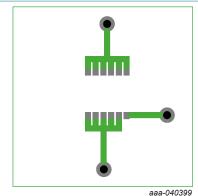


9. Thermal characteristics

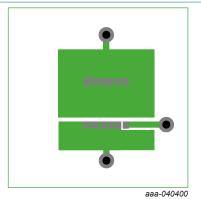
Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	Fig. 5	-	0.075	0.1	K/W
$R_{th(j-a)}$	thermal resistance from	Fig. 6	-	58	-	K/W
	junction to ambient	<u>Fig. 7</u>	-	29	-	K/W





70 µm thick copper on FR4 board Fig. 6. PCB layout with minimum footprint for thermal resistance from junction to ambient



Copper area 25.4 mm square; 70 µm thick on FR4 board

PCB layout for thermal resistance from junction Fig. 7. to ambient

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static charac	cteristics					
V _{(BR)DSS}	drain-source	I _D = 250 μA; V _{GS} = 0 V; T _j = 25 °C	80	-	-	V
	breakdown voltage	I _D = 250 μA; V _{GS} = 0 V; T _j = -55 °C	72	-	-	V
V _{GS(th)}	gate-source threshold	I _D = 1 mA; V _{DS} =V _{GS} ; T _j = 25 °C	2	2.8	3.6	V
	voltage	I _D = 1 mA; V _{DS} =V _{GS} ; T _j = 175 °C	-	1.71	-	V
		$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = -55 \text{ °C}$	-	3.2	-	V
$\Delta V_{GS(th)}/\Delta T$	gate-source threshold voltage variation with temperature	25 °C ≤ T _j ≤ 150 °C	-	-6.92	-	mV/K
I _{DSS}	drain leakage current	V _{DS} = 80 V; V _{GS} = 0 V; T _j = 25 °C	-	0.19	2	μΑ
		V _{DS} = 80 V; V _{GS} = 0 V; T _j = 125 °C	-	42	200	μΑ
I _{GSS}	gate leakage current	V _{GS} = 20 V; V _{DS} = 0 V; T _j = 25 °C	-	2	100	nA
		V _{GS} = -20 V; V _{DS} = 0 V; T _i = 25 °C	-	2	100	nA
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 25 A; T _j = 25 °C; Fig. 11	-	0.76	0.95	mΩ
		V_{GS} = 10 V; I_D = 25 A; T_j = 100 °C; Fig. 12	-	1.2	1.5	mΩ
		V_{GS} = 10 V; I_D = 25 A; T_j = 175 °C; Fig. 12	-	1.6	2.2	mΩ
R _G	gate resistance	f = 1 MHz; T _j = 25 °C	0.67	1.35	2.69	Ω
Dynamic cha	aracteristics		,			
Q _{G(tot)}	total gate charge	I _D = 25 A; V _{DS} = 40 V; V _{GS} = 10 V; T _j = 25 °C; <u>Fig. 13</u> ; <u>Fig. 14</u>	168	336	504	nC
		$I_D = 0 \text{ A}; V_{DS} = 0 \text{ V}; V_{GS} = 10 \text{ V};$ $T_j = 25 \text{ °C}$	-	305	-	nC
Q _{GS}	gate-source charge	I _D = 25 A; V _{DS} = 40 V; V _{GS} = 10 V;	68	113	158	nC
Q _{GS(th)}	pre-threshold gate- source charge	T _j = 25 °C; <u>Fig. 13; Fig. 14</u>	-	74.5	-	nC
Q _{GS(th-pl)}	post-threshold gate- source charge		-	38	-	nC
Q_{GD}	gate-drain charge		13	42.5	98	nC
V _{GS(pl)}	gate-source plateau voltage	I _D = 25 A; V _{DS} = 40 V; T _j = 25 °C; Fig. 13; Fig. 14	-	4.5	-	V
C _{iss}	input capacitance	V _{DS} = 40 V; V _{GS} = 0 V; f = 0.5 MHz;	15772	26287	36802	pF
C _{oss}	output capacitance	T _j = 25 °C; <u>Fig. 15</u>	3684	6139	9823	pF
C _{rss}	reverse transfer capacitance		16	163	489	pF
t _{d(on)}	turn-on delay time	$V_{DS} = 40 \text{ V}; R_L = 1.6 \Omega; V_{GS} = 10 \text{ V};$	-	95	-	ns
t _r	rise time	$R_{G(ext)} = 5 \Omega; T_j = 25 ^{\circ}C$	-	84	-	ns
t _{d(off)}	turn-off delay time	1	-	205	-	ns
t _f	fall time	1	-	107	-	ns
Source-drain	ı diode		<u> </u>	1	1	1
V_{SD}	source-drain voltage	I _S = 25 A; V _{GS} = 0 V; T _i = 25 °C; <u>Fig. 16</u>		0.76	1	V

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
t _{rr}	_	$I_S = 25 \text{ A}; dI_S/dt = -100 \text{ A/}\mu\text{s}; V_{GS} = 0 \text{ V};$	-	75	-	ns
Q _r	recovered charge	V _{DS} = 40 V; T _j = 25 °C; <u>Fig. 17</u>	-	101	-	nC

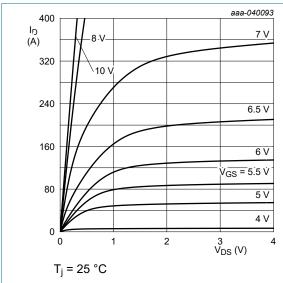


Fig. 8. Output characteristics; drain current as a function of drain-source voltage; typical values

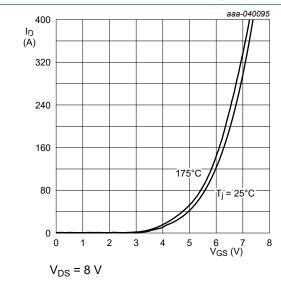


Fig. 10. Transfer characteristics; drain current as a function of gate-source voltage; typical values

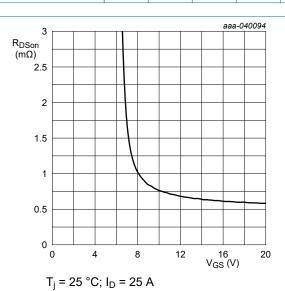


Fig. 9. Drain-source on-state resistance as a function of gate-source voltage; typical values

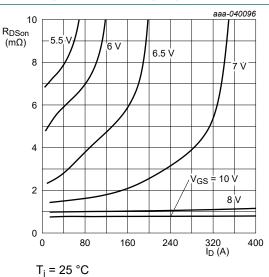


Fig. 11. Drain-source on-state resistance as a function of drain current; typical values

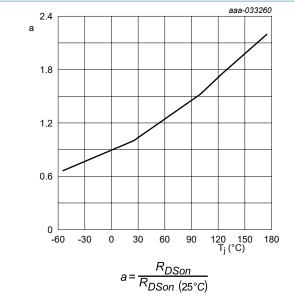


Fig. 12. Normalized drain-source on-state resistance factor as a function of junction temperature

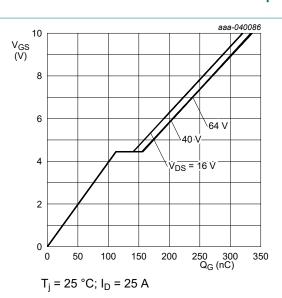


Fig. 13. Gate-source voltage as a function of gate charge; typical values

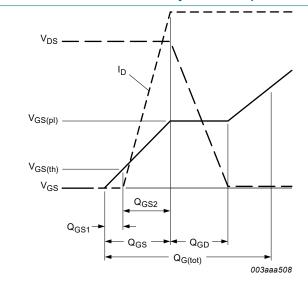
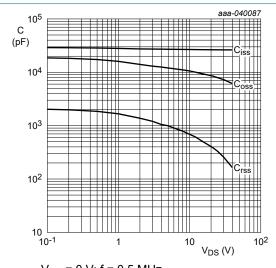


Fig. 14. Gate charge waveform definitions



V_{GS} = 0 V; f = 0.5 MHz

Fig. 15. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

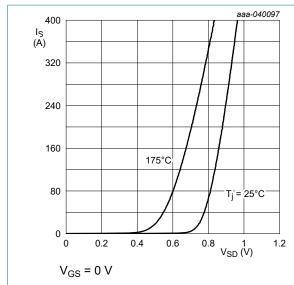


Fig. 16. Source-drain (diode forward) current as a function of source-drain (diode forward) voltage; typical values

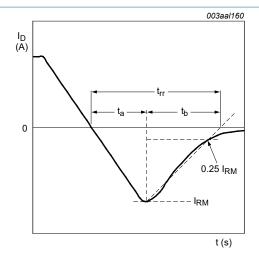
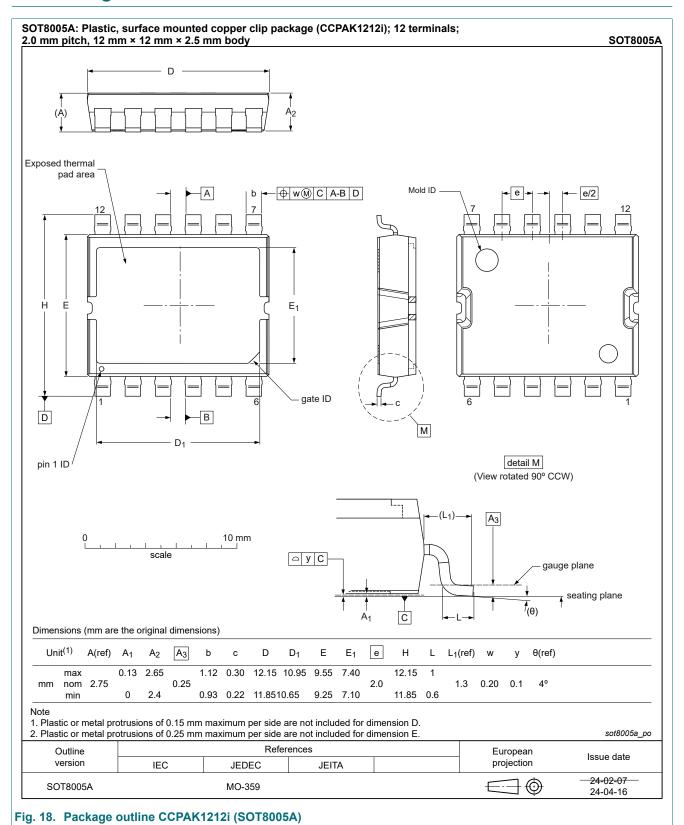
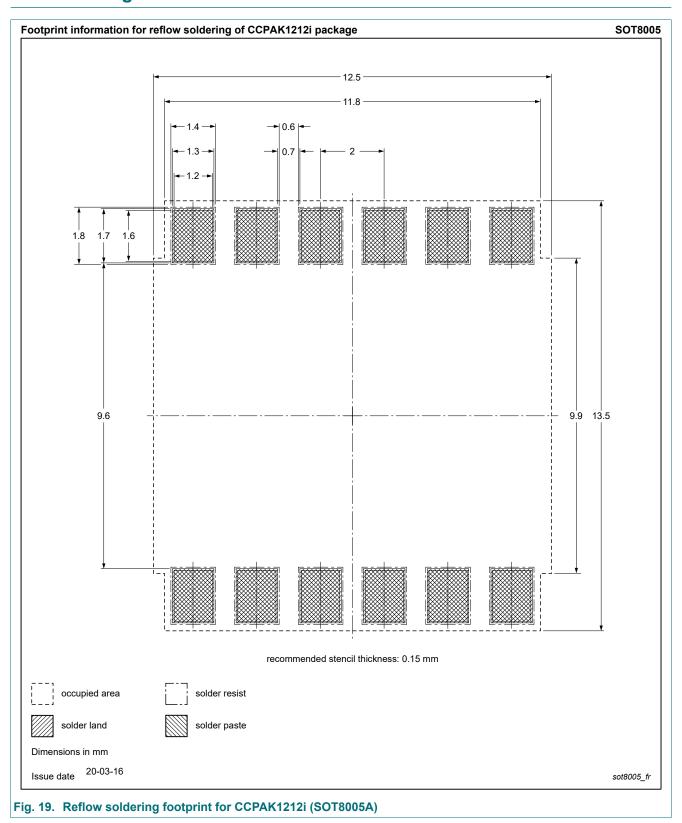


Fig. 17. Reverse recovery timing definition

11. Package outline



12. Soldering



13. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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